# NSN 5961-00-914-7857

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## Inclosure Material:

Metal

# **Overall Length:**

Between 0.320 inches and 0.468 inches

# Mounting Facility Quantity:

1

## Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

## **Mounting Method:**

Threaded stud

Features Provided:

Hermetically sealed case

## **Overall Width Across Flats:**

Between 0.424 inches and 0.437 inches

### Thread Size:

0.190 inches

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

150.0 collector to base voltage/static/emitter open and 100.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage, static, collector open

## **Current Rating Per Characteristic:**

Between 2.00 amperes source cutoff current and 2.00 amperes source cutoff current and 2.00 amperes source cutoff current blank

## Power Rating Per Characteristic:

30.0 watts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius case

### **Special Features:**

Junction pattern arrangement: npn

### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## Thread Series Designator:

Unf

Terminal Type And Quantity: 3 tab, solder lug Specification Data: 81349-mil-s-19500/277 government specification Shelf Life:

N/a

# Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

